



### Single Coin-cell Battery Transmitter

- Supply voltage: 1.8 to 3.6 V
- Standby current < 10 nA
- Crystal-less operation:
  - ±150 ppm 0 to +70°C
  - ±250 ppm -40 to +85°C
- Temperature range -40 to +85 °C
- Automotive grade available
- 10P MSOP/14P SOIC
- Pb free/RoHS compliant

#### **RF Transmitter**

- Frequency range: 27-960 MHz
- +10 dBm output power, adjustable
- Automatic antenna tuning
- Symbol rate up to 100 kBaud
- FSK/OOK modulation
- Manchester, NRZ, 4/5 encoder

#### **Analog Peripherals**

- LDO regulator with POR circuit
- Integrated temperature sensor
- Low battery detector

### High-Speed 8051 µC Core

- Pipeline instruction architecture
- 70% of instructions in 1 or 2 clocks
- Up to 24 MIPs with 24 MHz clock

### Memory

- 4 kB RAM/8K NVM
- 128 bit EEPROM
- 256 byte of internal data RAM
- 256 byte of external data RAM (XREG)
- 12 kB ROM embedded functions
- 8 byte low leakage RAM (preserved in standby)

**Crystal-less SoC RF Transmitter** 

### **Digital Peripherals**

- 128 bit AES Accelerator
- 4/8 GPIO with wake-up functionality
- 1 LFD driver
- Data serializer
- High-speed frequency counter
- RTC, Timers 2, 3
- On-chip debugging—C2

#### Clock Sources

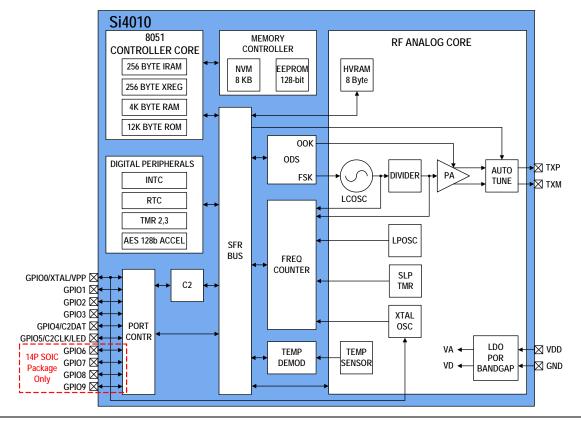
- High-speed crystal-less VCO
- Programmable low-power osc-LPOSC
- Ultra low-power sleep timer
- Optional crystal input for tigher tolerances

#### Minimal External BOM

- Only one external component required

#### **Applications**

- Garage and gate door openers
- Home automation and security
- Remote keyless entry





# **Crystal-less SoC RF Transmitter**

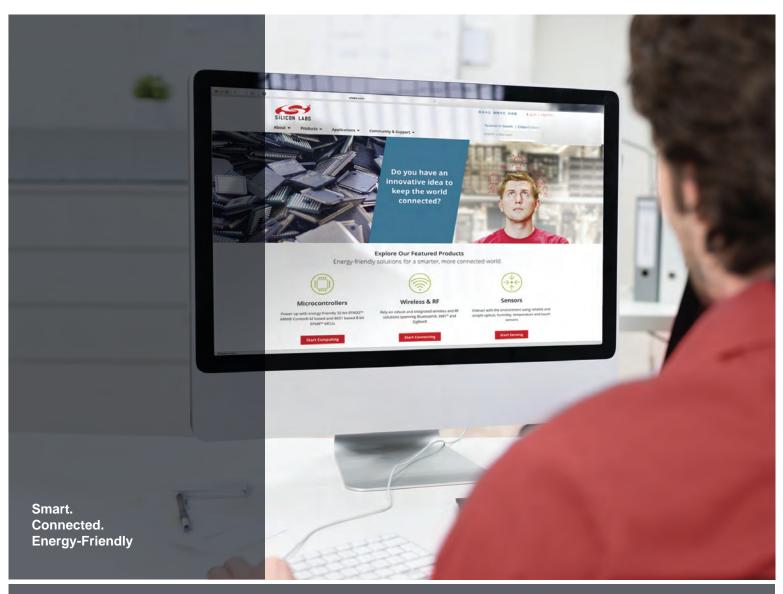
## **Selected Electrical Specifications**

Parameter Symbol C		Conditions	Min	Тур	Max	Units
Supply Voltage	$V_{DD}$		1.8	_	3.6	V
Supply Current	$I_{VDD}$	+10 dBm output, OOK, Manchester	_	14.2	_	mA
		+6.5 dBm output, OOK, Manchester	_	11.3	_	mA
		+10 dBm, FSK		19.8	_	mA
		+6.5 dBm output, FSK		14.1	_	mA
Sleep Timer Mode	I <sub>ST</sub>	Only sleep timer is enabled		700	_	nA
Standby Current	I <sub>SB</sub>	All GPIO floating or held high	_	10	_	nA
Frequency Range	F <sub>RF</sub>		27		960	MHz
Frequency Noise (rms)		Allen deviation measured across 1ms interval	_	0.3	_	ppm
Frequency Tuning Time			_	5	_	ms
Carrier Frequency Accuracy		$27 \text{ MHz} \le F_{RF} \le 960 \text{ MHz}$ $0^{\circ}\text{C} \le T_{A} \le 70^{\circ}\text{ C}$	<b>–150</b>	_	+150	ppm
		27 MHz ≤ F <sub>RF</sub> ≤ 960 MHz -40°C ≤ T <sub>A</sub> ≤ 85° C	<b>–</b> 250	_	+250	ppm
		Error contribution using optional crystal input	-10	_	+10	ppm
Transmit Power		Maximum programmed transmit power	_	10	_	dBm
		Minimum programmed transmit power	_	-13	_	dBm
		Power variation vs temp and supply, with optimum load and $V_{dd} > 2.2V$	-1.0	_	+0.5	dB
		Power variation vs temp and supply, with optimum load and $V_{dd} > 1.8V$	-2.5	_	+0.5	dB
		Step size from -13 to +6.5 dBm	_	0.25	_	dB
PA Edge Ramp Rate Programmable Range		OOK mode	0.34	_	10.7	μs
Data Rate		FSK	0.1	<del>  _  </del>	100	kBaud
		OOK (Manchester)	0.1	_	50	kBaud

## 10-pin MSOP Package

## 14-pin SOIC Package

GPIO0/XTAL 1	) 2 1 3 Si4010-GT	10 GPI01	GPI09 1		14 GPI08
GND 2		9 GPIO2	GPIO0/XTAL 2		13 GPIO1
TXM 3		8 GPIO3 7 GPIO4	GND 3	Si4010-GS	12 GPIO2
			TXM 4		11 GPIO3
TXP 4			TXP 5		10 GPIO4
VDD 5		6 LED	VDD 6		9 LED
			GPIO7 7		8 GPI06









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